# **ON Semiconductor**

# Is Now



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# 3 W DO-41 Surmetic 30 Zener Voltage Regulators

This is a complete series of 3 W Zener diodes with limits and excellent operating characteristics that reflect the superior capabilities of silicon-oxide passivated junctions. All this in an axial-lead, transfer-molded plastic package that offers protection in all common environmental conditions.

#### **Features**

- Zener Voltage Range 3.3 V to 200 V
- ESD Rating of Class 3 (>16 KV) per Human Body Model
- Surge Rating of 98 W @ 1 ms
- Maximum Limits Guaranteed on up to Six Electrical Parameters
- Package No Larger than the Conventional 1 W Package
- Pb-Free Packages are Available

#### **Mechanical Characteristics**

CASE: Void free, transfer-molded, thermosetting plastic

FINISH: All external surfaces are corrosion resistant and leads are

readily solderable

#### **MAXIMUM LEAD TEMPERATURE FOR SOLDERING PURPOSES:**

260°C, 1/16" from the case for 10 seconds

POLARITY: Cathode indicated by polarity band

**MOUNTING POSITION: Any** 

#### **MAXIMUM RATINGS**

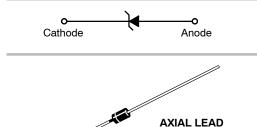
Rating	Symbol	Value	Unit
Max. Steady State Power Dissipation @ T <sub>L</sub> = 75°C, Lead Length = 3/8"	P <sub>D</sub>	3	W
Derate above 75°C		24	mW/°C
Steady State Power Dissipation @ T <sub>A</sub> = 50°C	P <sub>D</sub>	1	W
Derate above 50°C		6.67	mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 65 to +200	ç

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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#### **MARKING DIAGRAM**

**CASE 59** 

PLASTIC STYLE 1



A = Assembly Location 1N59xxB = Device Number

YY = Year WW = Work Week Pb- Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
1N59xxB, G	Axial Lead (Pb-Free)	2000 Units/Box
1N59xxBRL, G	Axial Lead (Pb-Free)	6000/Tape & Reel

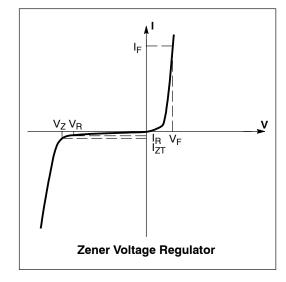
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb- Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **ELECTRICAL CHARACTERISTICS**

 $(T_L = 30^{\circ}\text{C unless otherwise noted}, V_F = 1.5 \text{ V Max } @ I_F = 200 \text{ mAdc for all types})$ 

Symbol	Parameter
VZ	Reverse Zener Voltage @ I <sub>ZT</sub>
I <sub>ZT</sub>	Reverse Current
Z <sub>ZT</sub>	Maximum Zener Impedance @ I <sub>ZT</sub>
I <sub>ZK</sub>	Reverse Current
Z <sub>ZK</sub>	Maximum Zener Impedance @ I <sub>ZK</sub>
I <sub>R</sub>	Reverse Leakage Current @ V <sub>R</sub>
$V_R$	Breakdown Voltage
IF	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>
I <sub>ZM</sub>	Maximum DC Zener Current



**ELECTRICAL CHARACTERISTICS** ( $T_L = 30^{\circ}C$  unless otherwise noted,  $V_F = 1.5 \text{ V}$  Max @  $I_F = 200 \text{ mAdc}$  for all types)

		Zener Voltage (Note 2)		Zener Impedance (Note 3)		Leakage Current					
Device <sup>†</sup>	Device	,	V <sub>Z</sub> (Volts)	)	@ I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> @	و ا	I <sub>R</sub> @	V <sub>R</sub>	I <sub>ZM</sub>
(Note 1)	Marking	Min	Nom	Max	mA	Ω	Ω	mA	μ <b>Α Max</b>	Volts	mA
1N5913B, G	1N5913B	3.14	3.3	3.47	113.6	10	500	1	100	1	454
1N5917B, G	1N5917B	4.47	4.7	4.94	79.8	5	500	1	5	1.5	319
1N5919B, G	1N5919B	5.32	5.6	5.88	66.9	2	250	1	5	3	267
1N5920B, G	1N5920B	5.89	6.2	6.51	60.5	2	200	1	5	4	241
1N5921B, G	1N5921B	6.46	6.8	7.14	55.1	2.5	200	1	5	5.2	220
1N5923B, G	1N5923B	7.79	8.2	8.61	45.7	3.5	400	0.5	5	6.5	182
1N5924B, G	1N5924B	8.65	9.1	9.56	41.2	4	500	0.5	5	7	164
1N5925B, G	1N5925B	9.50	10	10.50	37.5	4.5	500	0.25	5	8	150
1N5926B, G	1N5926B	10.45	11	11.55	34.1	5.5	550	0.25	1	8.4	136
1N5927B, G	1N5927B	11.40	12	12.60	31.2	6.5	550	0.25	1	9.1	125
1N5929B, G	1N5929B	14.25	15	15.75	25.0	9	600	0.25	1	11.4	100
1N5930B, G	1N5930B	15.20	16	16.80	23.4	10	600	0.25	1	12.2	93
1N5931B, G	1N5931B	17.10	18	18.90	20.8	12	650	0.25	1	13.7	83
1N5932B, G	1N5932B	19.00	20	21.00	18.7	14	650	0.25	1	15.2	75
1N5933B, G	1N5933B	20.90	22	23.10	17.0	17.5	650	0.25	1	16.7	68
1N5934B, G	1N5934B	22.80	24	25.20	15.6	19	700	0.25	1	18.2	62
1N5935B, G	1N5935B	25.65	27	28.35	13.9	23	700	0.25	1	20.6	55
1N5936B, G	1N5936B	28.50	30	31.50	12.5	28	750	0.25	1	22.8	50
1N5937B, G	1N5937B	31.35	33	34.65	11.4	33	800	0.25	1	25.1	45
1N5938B, G	1N5938B	34.20	36	37.80	10.4	38	850	0.25	1	27.4	41
1N5940B, G	1N5940B	40.85	43	45.15	8.7	53	950	0.25	1	32.7	34
1N5941B, G	1N5941B	44.65	47	49.35	8.0	67	1000	0.25	1	35.8	31
1N5942B, G	1N5942B	48.45	51	53.55	7.3	70	1100	0.25	1	38.8	29
1N5943B, G	1N5943B	53.20	56	58.80	6.7	86	1300	0.25	1	42.6	26
1N5944B, G	1N5944B	58.90	62	65.10	6.0	100	1500	0.25	1	47.1	24
1N5946B, G	1N5946B	71.25	75	78.75	5.0	140	2000	0.25	1	56	20
1N5947B, G	1N5947B	77.90	82	86.10	4.6	160	2500	0.25	1	62.2	18
1N5948B, G	1N5948B	86.45	91	95.55	4.1	200	3000	0.25	1	69.2	16
1N5950B, G	1N5950B	104.5	110	115.5	3.4	300	4000	0.25	1	83.6	13
1N5951B, G	1N5951B	114	120	126	3.1	380	4500	0.25	1	91.2	12
1N5952B, G	1N5952B	123.5	130	136.5	2.9	450	5000	0.25	1	98.8	11
1N5953B, G	1N5953B	142.5	150	157.5	2.5	600	6000	0.25	1	114	10
1N5954B, G	1N5954B	152	160	168	2.3	700	6500	0.25	1	121.6	9
1N5955B, G	1N5955B	171	180	189	2.1	900	7000	0.25	1	136.8	8
1N5956B, G	1N5956B	190	200	210	1.9	1200	8000	0.25	1	152	7

Devices listed in **bold**, **italic** are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

ON Semiconductor guarantees the zener voltage when measured at 90 seconds while maintaining the lead temperature (T<sub>L</sub>) at 30°C ±1°C, 3/8" from the diode body.

3. ZENER IMPEDANCE (Z<sub>Z</sub>) DERIVATION

The zener impedance is derived from 60 seconds AC voltage, which results when an AC current having an rms value equal to 10% of the DC zener current ( $I_{ZT}$  or  $I_{ZK}$ ) is superimposed on  $I_{ZT}$  or  $I_{ZK}$ .

<sup>†</sup>The "G" suffix indicates Pb- Free package available.

1. TOLERANCE AND TYPE NUMBER DESIGNATION

Tolerance designation - device tolerance of  $\pm 5\%$  are indicated by a "B" suffix. 2. **ZENER VOLTAGE (V<sub>Z</sub>) MEASUREMENT** 

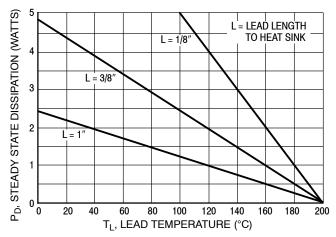


Figure 1. Power Temperature Derating Curve

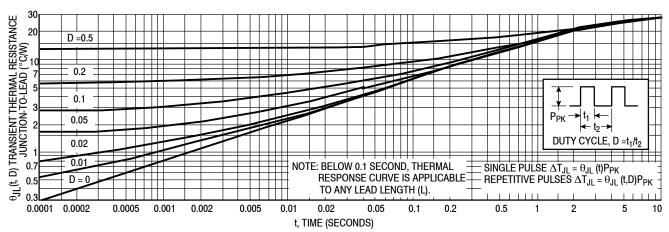


Figure 2. Typical Thermal Response L, Lead Length = 3/8 Inch

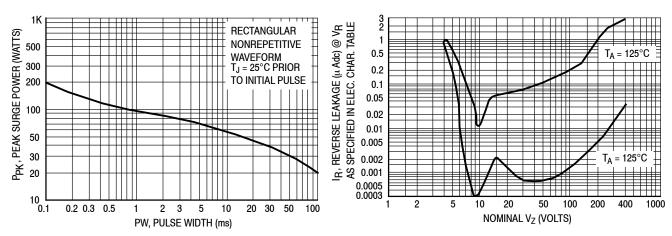


Figure 3. Maximum Surge Power

Figure 4. Typical Reverse Leakage

#### **APPLICATION NOTE**

Since the actual voltage available from a given zener diode is temperature dependent, it is necessary to determine junction temperature under any set of operating conditions in order to calculate its value. The following procedure is recommended:

Lead Temperature, T<sub>L</sub>, should be determined from:

$$T_I = \theta_{IA} P_D + T_A$$

 $\theta_{LA}$  is the lead-to-ambient thermal resistance (°C/W) and  $P_D$  is the power dissipation. The value for  $\theta_{LA}$  will vary and depends on the device mounting method.  $\theta_{LA}$  is generally 30-40°C/W for the various clips and tie points in common use and for printed circuit board wiring.

The temperature of the lead can also be measured using a thermocouple placed on the lead as close as possible to the tie point. The thermal mass connected to the tie point is normally large enough so that it will not significantly respond to heat surges generated in the diode as a result of pulsed operation once steady-state conditions are achieved. Using the measured value of  $T_L$ , the junction temperature may be determined by:

$$T_J = T_L + \Delta T_{JL}$$

 $\Delta T_{JL}$  is the increase in junction temperature above the lead temperature and may be found from Figure 2 for a train of power pulses (L = 3/8 inch) or from Figure 10 for dc power.

$$\Delta T_{JL} = \theta_{JL} P_D$$

For worst-case design, using expected limits of  $I_Z$ , limits of  $P_D$  and the extremes of  $T_J$  ( $\Delta T_J$ ) may be estimated. Changes in voltage,  $V_Z$ , can then be found from:

$$\Delta V = \theta_{VZ} \Delta T_{J}$$

 $\theta_{VZ}\!,$  the zener voltage temperature coefficient, is found from Figures 5 and 6.

Under high power-pulse operation, the zener voltage will vary with time and may also be affected significantly by the zener resistance. For best regulation, keep current excursions as low as possible.

Data of Figure 2 should not be used to compute surge capability. Surge limitations are given in Figure 3. They are lower than would be expected by considering only junction temperature, as current crowding effects cause temperatures to be extremely high in small spots resulting in device degradation should the limits of Figure 3 be exceeded.

#### **TEMPERATURE COEFFICIENT RANGES**

(90% of the Units are in the Ranges Indicated)

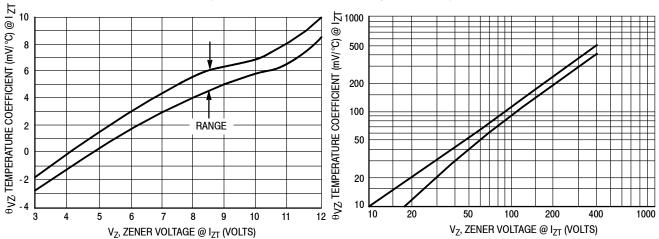


Figure 5. Units To 12 Volts

Figure 6. Units 10 To 400 Volts

### **ZENER VOLTAGE versus ZENER CURRENT**

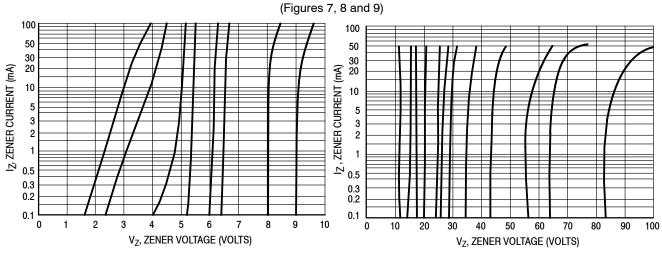


Figure 7.  $V_Z = 3.3$  thru 10 Volts

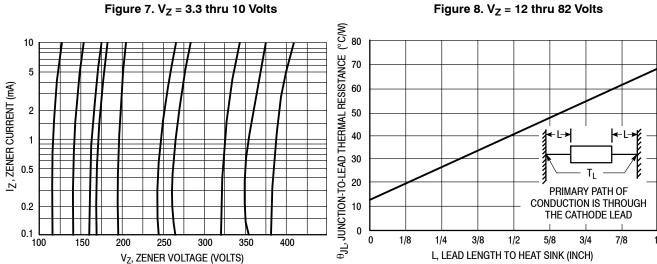
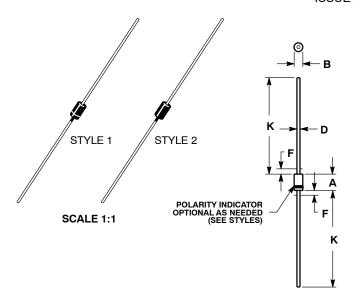


Figure 9. V<sub>Z</sub> = 100 thru 400 Volts

Figure 10. Typical Thermal Resistance

#### **AXIAL LEAD** CASE 59-10 **ISSUE U**

**DATE 15 FEB 2005** 

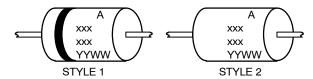


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

- CONTROLLING DIMENSION: INCH.
  ALL RULES AND NOTES ASSOCIATED WITH
  JEDEC DO-41 OUTLINE SHALL APPLY
  POLARITY DENOTED BY CATHODE BAND.
  LEAD DIAMETER NOT CONTROLLED WITHIN F
  DIMENSION.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.161	0.205	4.10	5.20	
В	0.079	0.106	2.00	2.70	
D	0.028	0.034	0.71	0.86	
F		0.050		1.27	
K	1.000		25.40		

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code = Assembly Location Α

YY = Year WW = Work Week

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1: PIN 1. CATHODE (POLARITY BAND) STYLE 2: NO POLARITY 2. ANODE

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